



ZXT10P40DE6

40V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26

Features

- BV_{CEO} > -40V
- I_C = -2A Continuous Collector Current
- I_{CM} = -4A Peak Pulse Current
- $R_{CE(sat)} = 105m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage of <-220mV @ -1A
- hFE Characterized up to -3A for High Current Gain Hold-Up
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

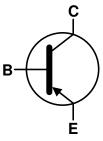
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight: 0.015 grams (Approximate)

Applications

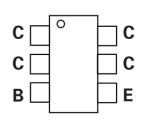
- DC-DC Converters
- Power Management Functions
- Power Switches
- Motor Control







Device Symbol



Pin-Out Top

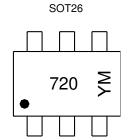
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT10P40DE6TA	720	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



720 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: D = 2016) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	201	6	2017	2018	2019	2020	2021	202	2 20	23 2	2024	2025	2026
Code	D		Е	F	G	Η		J	ŀ	<	L	М	N
Month	1	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code		1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5	V
Base Current	I _B	-500	mA
Continuous Collector Current	Ic	-2	Α
Peak Pulse Collector Current	I _{CM}	-4	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)		1.1 8.8	W	
Linear Derating Factor	(Note 6)	PD	1.7 13.6	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 5) (Note 6)	R _{0JA}	113 73	°C/W	
Thermal Resistance, Junction to Lead (Note 7)		R ₀ JL	18.61	O/ VV	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

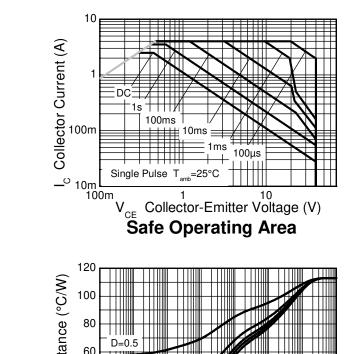
^{5.} For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

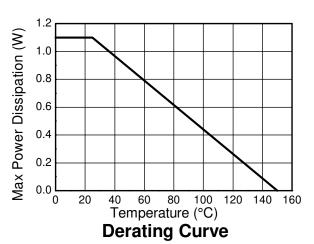
^{6.} Same as Note 5, except the device is measured at $t \le 5$ seconds.

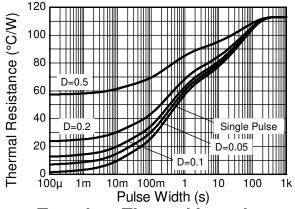
^{8.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information







Transient Thermal Impedance



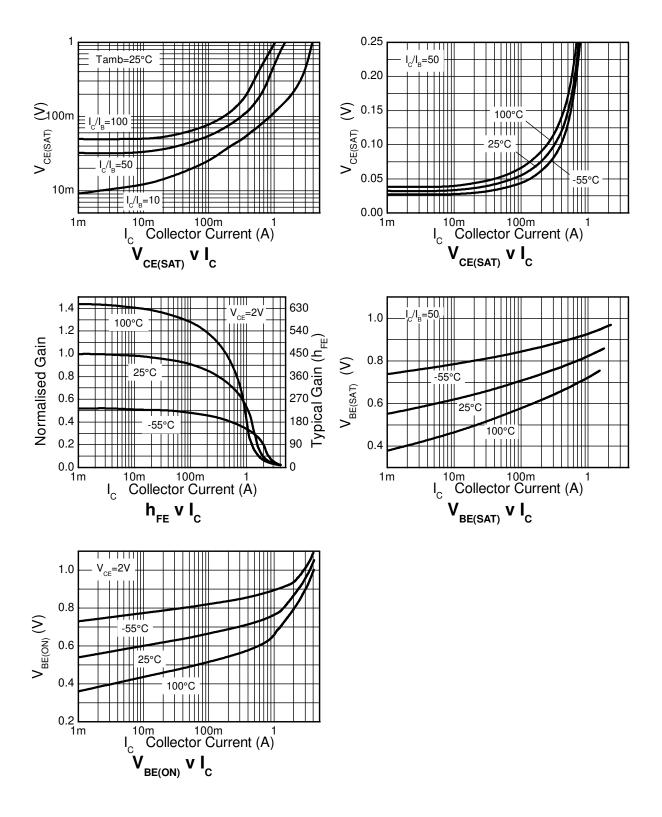
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage	BV _{CBO}	-40	-80	_	V	$I_{C} = -100 \mu A$	
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-40	-70		V	$I_C = -10mA$	
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	-8.8	_	V	I _E = -100μA	
Collector-Base Cut-Off Current	I _{CBO}	_		-100	nA	$V_{CB} = -35V$	
Emitter Cut-Off Current	I _{EBO}	_	_	-100	nA	V _{EB} = -4V	
Collector-Emitter Cut-Off Current	I _{CES}	_		-100	nA	V _{CES} = -35V	
ON CHARACTERISTICS (Note 9)							
		300	480	_	_	$I_C = -10$ mA, $V_{CE} = -2$ V	
		300	450			$I_C = -100 \text{mA}, V_{CE} = -2 \text{V}$	
DC Current Gain	h _{FE}	180	290	_	_	$I_C = -1A$, $V_{CE} = -2V$	
		60	130	_	_	$I_C = -1.5A, V_{CE} = -2V$	
		12	22	_	_	$I_{C} = -3A, V_{CE} = -2V$	
		_	-25	-40		I _C = -100mA, I _B = -10mA	
		_	-150	-220	mV	I _C = -1A, I _B = -100mA	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	-195	-300		$I_C = -1.5A$, $I_B = -100mA$	
		_	-210	-300		I _C = -2A, I _B = -200mA	
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	-0.95	-1.0	V	I _C = -2A, I _B = -200mA	
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	-0.85	-0.95	V	I _C = -2A, V _{CE} = -2V	
SMALL SIGNAL CHARACTERISTICS	- 10 - 10 - 10 - 10 - 10 - 10 - 10 - 10						
Current Gain-Bandwidth Product	f⊤	150	190	_	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz	
Output Capacitance	C_{obo}	_	19	25	pF	V _{CB} = -10V, f = 1MHz	
Turn-On Time	t _(on)	_	40	_	ns	V _{CC} = -15V, I _C = -0.75A	
Turn-Off Time	t _(off)	_	435	_	ns	$I_{B1} = I_{B2} = -15mA$	

Note: 9. Measured under pulsed conditions; pulse width $\leq 300 \mu s$, duty cycle $\leq 2\%$.



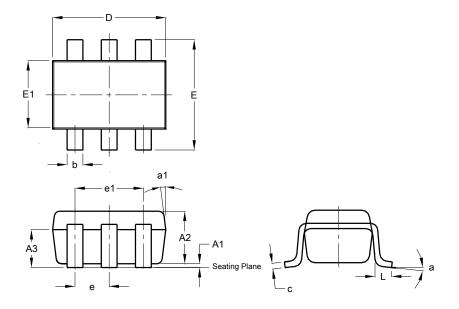
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





Package Outline Dimensions

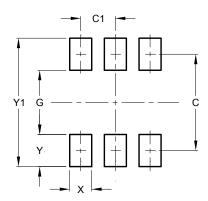
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT26						
Dim	Min	Max	Тур			
A1	0.013	0.10	0.05			
A2	1.00	1.30	1.10			
А3	0.70	0.80	0.75			
b	0.35	0.50	0.38			
С	0.10	0.20	0.15			
D	2.90	3.10	3.00			
е	-	-	0.95			
e1	-	-	1.90			
Е	2.70	3.00	2.80			
E1	1.50	1.70	1.60			
L	0.35	0.55	0.40			
а	-	-	8°			
a1	-	-	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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